

74ACT164

Serial-In, Parallel-Out Shift Register

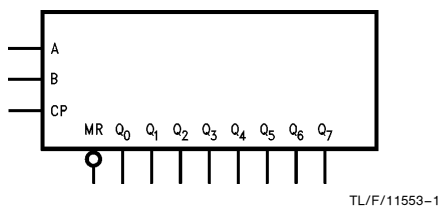
General Description

The 74ACT164 is a high-speed 8-bit serial-in/parallel-out shift register. Serial data is entered through a 2-input AND gate synchronous with the Low-to-High transition of the clock. The device features an asynchronous Master Reset which clears the register, setting all outputs Low independent of the clock.

Features

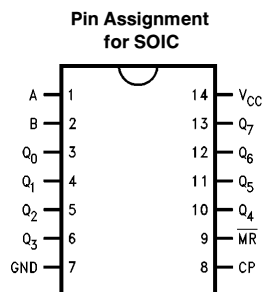
- Outputs source/sink 24 mA
- 'ACT has TTL-compatible inputs

Logic Symbol



Pin Names	Description
A, B	Data Inputs
CP	Clock Pulse Input (Active Rising Edge)
$\overline{\text{MR}}$	Master Reset Input (Active Low)
Q_0 – Q_7	Outputs

Connection Diagram



Functional Description

The 74ACT164 is an edge-triggered 8-bit shift register with serial data entry and an output from each of the eight stages. Data is entered serially through one of two inputs (A or B); either of these inputs can be used as an active High Enable for data entry through the other input. An unused input must be tied High.

Each Low-to-High transition on the Clock (CP) input shifts data one place to the right and enters into Q_0 the logical AND of the two data inputs ($A \bullet B$) that existed before the rising clock edge. A Low level on the Master Reset (\overline{MR}) input overrides all other inputs and clears the register asynchronously, forcing all Q outputs Low.

Function Table

Operating Mode	Inputs			Outputs	
	\overline{MR}	A	B	Q_0	Q_1-Q_7
Reset (Clear)	L	X	X	L	L-L
Shift	H	L	L	L	Q_0-Q_6
	H	L	H	L	Q_0-Q_6
	H	H	L	L	Q_0-Q_6
	H	H	H	H	Q_0-Q_6

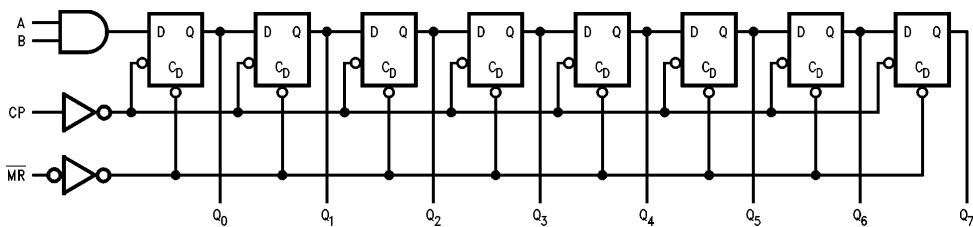
H = High Voltage Levels

L = Low Voltage Levels

X = Immaterial

Q = Lower case letters indicate the state of the referenced input or output one setup time prior to the Low-to-High clock transition.

Logic Diagram



TL/F/11553-3

Please note that this diagram is provided only for the understanding of logic operations and should not be used to estimate propagation delays.

Absolute Maximum Ratings (Note 1)

If Military/Aerospace specified devices are required, please contact the National Semiconductor Sales Office/Distributors for availability and specifications.

Supply Voltage (V_{CC})	−0.5V to +7.0V
DC Input Diode Current (I_{IK})	−20 mA
$V_I = -0.5V$	−20 mA
$V_I = V_{CC} + 0.5V$	+20 mA
DC Input Voltage (V_I)	−0.5V to $V_{CC} + 0.5V$
DC Output Diode Current (I_{OK})	−20 mA
$V_O = -0.5V$	−20 mA
$V_O = V_{CC} + 0.5V$	+20 mA
DC Output Voltage (V_O)	−0.5V to $V_{CC} + 0.5V$
DC Output Source or Sink Current (I_O)	±50 mA
DC V_{CC} or Ground Current per Output Pin (I_{CC} or I_{GND})	±50 mA
Storage Temperature (T_{STG})	−65°C to +150°C
Junction Temperature (T_J)	140°C
SOIC	140°C

Note 1: Absolute maximum ratings are values beyond which damage to the device may occur. The databook specifications should be met, without exception, to ensure that the system design is reliable over its power supply, temperature, and output/input loading variables. National does not recommend operation of FACT™ circuits outside databook specifications.

Recommended Operating Conditions

Supply Voltage (V_{CC})	4.5V to 5.5V
'ACT	
Input Voltage (V_I)	0V to V_{CC}
Output Voltage (V_O)	0V to V_{CC}
Operating Temperature (T_A)	−40°C to +85°C
74ACT	
Minimum Input Edge Rate ($\Delta V/\Delta t$)	
'ACT Devices	
V_{IN} from 0.8V to 2.0V	
V_{CC} @ 4.5V, 5.5V	125 mV/ns

DC Characteristics for 'ACT Family Devices

Symbol	Parameter	V _{CC} (V)	74ACT		74ACT	Units	Conditions
			T _A = +25°C		T _A = −40°C to +85°C		
			Typ	Guaranteed Limits			
V _{IH}	Minimum High Level Input Voltage	4.5	1.5	2.0	2.0	V	V _{OUT} = 0.1V or V _{CC} − 0.1V
		5.5	1.5	2.0	2.0		
V _{IL}	Maximum Low Level Input Voltage	4.5	1.5	0.8	0.8	V	V _{OUT} = 0.1V or V _{CC} − 0.1V
		5.5	1.5	0.8	0.8		
V _{OH}	Minimum High Level Output Voltage	4.5	4.49	4.4	4.4	V	I _{OUT} = −50 μA
		5.5	5.49	5.4	5.4		
		4.5		3.86	3.76	V	*V _{IN} = V _{IL} or V _{IH} −24 mA I _{OH} −24 mA
		5.5		4.86	4.76		
V _{OL}	Maximum Low Level Output Voltage	4.5	0.001	0.1	0.1	V	I _{OUT} = 50 μA
		5.5	0.001	0.1	0.1		
		4.5		0.36	0.44	V	*V _{IN} = V _{IL} or V _{IH} 24 mA I _{OL} 24 mA
		5.5		0.36	0.44		
I _{IN}	Maximum Input Leakage Current	5.5		±0.1	±1.0	μA	V _I = V _{CC} , GND
I _{CCT}	Maximum I _{CC} /Input	5.5	0.6		1.5	mA	V _I = V _{CC} − 2.1V
I _{OLD}	†Minimum Dynamic Output Current	5.5			75	mA	V _{OLD} = 1.65V Max
I _{OHD}		5.5			−75	mA	V _{OHD} = 3.85V Min
I _{CC}	Maximum Quiescent Supply Current	5.5		4.0	40.0	μA	V _{IN} = V _{CC} or GND

*All outputs loaded; thresholds on input associated with output under test.

†Maximum test duration 2.0 ms, one output loaded at a time.

AC Electrical Characteristics

Symbol	Parameter	V _{CC} * (V)	74ACT			74ACT		Units
			T _A = + 25°C C _L = 50 pF			T _A = − 40°C to + 85°C C _L = 50 pF		
			Min	Typ	Max	Min	Max	
f _{max}	Maximum Clock Frequency	5.0	100			80		MHz
t _{PLH}	Propagation Delay CP to Q _n	5.0	1.0	6.0	11.5	1.0	12.5	ns
t _{PHL}	Propagation Delay CP to Q _n	5.0	1.0	6.0	11.5	1.0	12.5	ns
t _{PHL}	Propagation Delay MR to Q _n	5.0	1.0	6.0	13.0	1.0	14.5	ns

*Voltage Range 5.0 is 5.0V ±0.5V

AC Operating Requirements

Symbol	Parameter	V _{CC} * (V)	74ACT		74ACT	Units
			T _A = +25°C C _L = 50 pF		T _A = −40°C to +85°C C _L = 50 pF	
			Typ	Guaranteed Minimum		
t _S	Set-Up Time, HIGH or LOW A or B to CP	5.0	0.5	7.0	8.0	ns
t _H	Hold Time, HIGH or LOW CP to A or B	5.0	0.0	1.5	1.5	ns
t _W	Pulse Width, HIGH or LOW CP to MR	5.0	0.5	7.0	8.0	ns
t _{REC}	Recovery Time MR to CP	5.0	0.5	2.0	2.0	ns

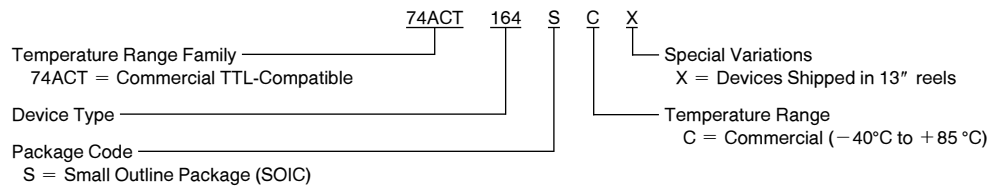
*Voltage Range 5.0 is 5.0V ±0.5V

Capacitance

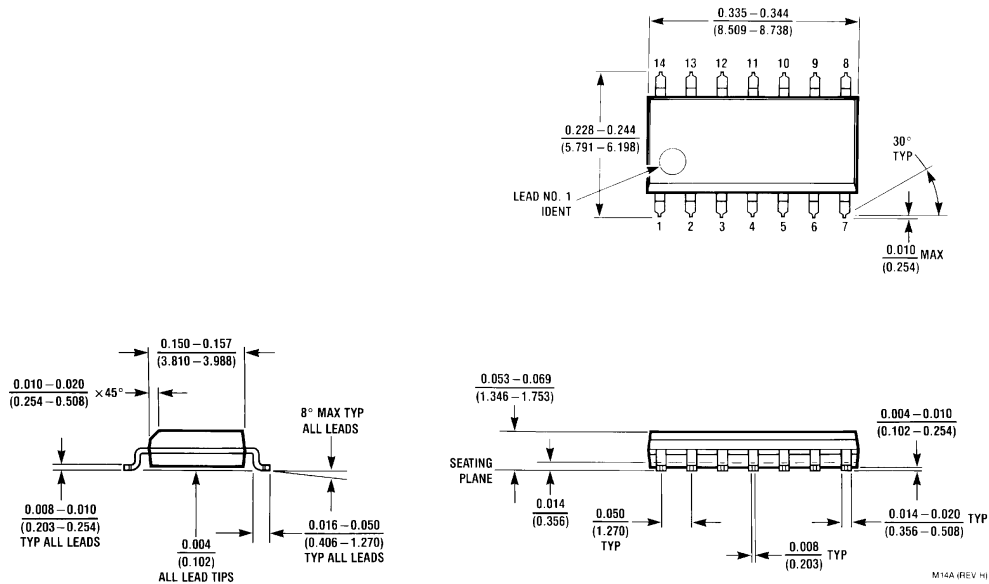
Symbol	Parameter	Typ	Units	Conditions
C _{IN}	Input Capacitance	4.5	pF	V _{CC} = OPEN
C _{PD}	Power Dissipation Capacitance	45.0	pF	V _{CC} = 5.0V

Ordering Information

The device number is used to form part of a simplified purchasing code where the package type and temperature range are defined as follows:



Physical Dimensions inches (millimeters)



14-Lead Small Outline Integrated Circuit (S)
NS Package Number M14A

LIFE SUPPORT POLICY

NATIONAL'S PRODUCTS ARE NOT AUTHORIZED FOR USE AS CRITICAL COMPONENTS IN LIFE SUPPORT DEVICES OR SYSTEMS WITHOUT THE EXPRESS WRITTEN APPROVAL OF THE PRESIDENT OF NATIONAL SEMICONDUCTOR CORPORATION. As used herein:

1. Life support devices or systems are devices or systems which, (a) are intended for surgical implant into the body, or (b) support or sustain life, and whose failure to perform, when properly used in accordance with instructions for use provided in the labeling, can be reasonably expected to result in a significant injury to the user.
2. A critical component is any component of a life support device or system whose failure to perform can be reasonably expected to cause the failure of the life support device or system, or to affect its safety or effectiveness.



National Semiconductor Corporation
2900 Semiconductor Drive
P.O. Box 58090
Santa Clara, CA 95052-8090
Tel: (408) 272-9959
TWX: (910) 339-9240

National Semiconductor GmbH
Livny-Gargan-Str. 10
D-82256 Fürstentfeldbruck
Germany
Tel: (81-41) 35-0
Telex: 527849
Fax: (81-41) 35-1

National Semiconductor Japan Ltd.
Sumitomo Chemical
Engineering Center
Bldg. 7F
1-7-1, Nakase, Mihamu-Ku
Chiba-City,
Chiba Prefecture 261
Tel: (043) 299-2300
Fax: (043) 299-2500

National Semiconductor Hong Kong Ltd.
13th Floor, Straight Block,
Ocean Centre, 5 Canton Rd.
Tsimshatsui, Kowloon
Hong Kong
Tel: (852) 2737-1600
Fax: (852) 2736-9960

National Semicondutores Do Brazil Ltda.
Rue Deputado Lacorda Franco
120-3A
Sao Paulo-SP
Brazil 05418-000
Tel: (55-11) 212-5066
Telex: 391-1131931 NSBR BR
Fax: (55-11) 212-1181

National Semiconductor (Australia) Pty. Ltd.
Building 16
Business Park Drive
Monash Business Park
Nottingham, Melbourne
Victoria 3168 Australia
Tel: (3) 558-9999
Fax: (3) 558-9998

National does not assume any responsibility for use of any circuitry described, no circuit patent licenses are implied and National reserves the right at any time without notice to change said circuitry and specifications.